



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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# Silicon Bridge Rectifier

$V_{RRM} = 50\text{ V} - 1000\text{ V}$   
 $I_F = 8\text{ A}$

## Features

- Types up to 1000 V  $V_{RRM}$
- Ideal for printed circuit board
- Low forward voltage drop
- High temperature soldering guaranteed: 250<sup>0</sup>C/ 10 seconds, 0.375" lead length
- Low leakage current

**BR-8 Package**



## Mechanical Data

Case: Molded plastic body

Polarity: Marked on body

Mounting position: Any

Mounting: Hole for number 6 screw

## Maximum ratings, at $T_j = 25\text{ }^\circ\text{C}$ , unless otherwise specified

Parameter	Symbol	Conditions	BR805	BR81	BR82	BR84	Unit
Repetitive peak reverse voltage	$V_{RRM}$		50	100	200	400	V
RMS reverse voltage	$V_{RMS}$		35	70	140	280	V
DC blocking voltage	$V_{DC}$		50	100	200	400	V
Continuous forward current	$I_F$	$T_C \leq 50\text{ }^\circ\text{C}$	8	8	8	8	A
Surge non-repetitive forward current, Half Sine Wave	$I_{F,SM}$	$T_C = 25\text{ }^\circ\text{C}$ , $t_p = 8.3\text{ ms}$	150	150	150	150	A
Operating temperature	$T_j$		-65 to 125	-65 to 125	-65 to 125	-65 to 125	$^\circ\text{C}$
Storage temperature	$T_{stg}$		-65 to 150	-65 to 150	-65 to 150	-65 to 150	$^\circ\text{C}$

## Electrical characteristics, at $T_j = 25\text{ }^\circ\text{C}$ , unless otherwise specified

Parameter	Symbol	Conditions	BR805	BR81	BR82	BR84	Unit
Diode forward voltage	$V_F$	$I_F = 4\text{ A}$ , $T_j = 25\text{ }^\circ\text{C}$	1.1	1.1	1.1	1.1	V
Reverse current	$I_R$	$V_R = 50\text{ V}$ , $T_j = 25\text{ }^\circ\text{C}$ $V_R = 50\text{ V}$ , $T_j = 100\text{ }^\circ\text{C}$	10 200	10 200	10 200	10 200	$\mu\text{A}$

